## NSN 5961-00-436-2288

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-436-2288 **Inclosure Material:** Metal **Overall Length:** 0.250 inches **Terminal Length:** 0.490 inches **Overall Diameter:** 0.352 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-76 **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 30.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source all transistor and 6.0 gate to source threshold voltage all transistor **Current Rating Per Characteristic:** 200.00 milliamperes zero-gate-voltage drain current all transistor **Power Rating Per Characteristic:** 600.0 milliwatts total device dissipation all transistor **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 8 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: